NSN 5961-01-468-0473

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-468-0473 **Inclosure Material:** Glass **Overall Length:** 5.880 millimeters **Overall Height:** 5.880 millimeters **Overall Width:** 1.450 millimeters **End Application:** Aircraft, awacs, e-3a **Mounting Facility Quantity: Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 4.0 working peak reverse voltage **Current Rating Per Characteristic:** 70.00 milliamperes source cutoff current universal **Power Rating Per Characteristic:** 200.0 milliwatts small-signal input power, common-emitter absolute **Maximum Operating Tempurature Per Measurement Point:** -55.0 degrees celsius case and 150.0 degrees celsius case **Terminal Type And Quantity:** 4 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:**

Demilitarization: No

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